Gate Driver
BM61M41RFV-C Evaluation Board
BM61M41RFV-EVK001

User's Guide

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＜High Voltage Safety Precautions＞

◇ Read all safety precautions before use

Please note that this document covers only the BM61M41RFV-C evaluation board (BM61M41RFV-EVK001) and its functions. For additional information, please refer to the datasheet.

To ensure safe operation, please carefully read all precautions before handling the evaluation board



Depending on the configuration of the board and voltages used,

Potentially lethal voltages may be generated.

Therefore, please make sure to read and observe all safety precautions described in the red box below.

Before Use

[1] Verify that the parts/components are not damaged or missing (i.e. due to the drops).
[2] Check that there are no conductive foreign objects on the board.
[3] Be careful when performing soldering on the module and/or evaluation board to ensure that solder splash does not occur.
[4] Check that there is no condensation or water droplets on the circuit board.

During Use

[5] Be careful to not allow conductive objects to come into contact with the board.
[6] **Brief accidental contact or even bringing your hand close to the board may result in discharge and lead to severe injury or death.**

Therefore, DO NOT touch the board with your bare hands or bring them too close to the board.
In addition, as mentioned above please exercise extreme caution when using conductive tools such as tweezers and screwdrivers.

[7] If used under conditions beyond its rated voltage, it may cause defects such as short-circuit or, depending on the circumstances, explosion or other permanent damages.
[8] Be sure to wear insulated gloves when handling is required during operation.

After Use

[9] The ROHM Evaluation Board contains the circuits which store the high voltage. Since it stores the charges even after the connected power circuits are cut, please discharge the electricity after using it, and please deal with it after confirming such electric discharge.
[10] Protect against electric shocks by wearing insulated gloves when handling.

This evaluation board is intended for use only in research and development facilities and should by handled **only by qualified personnel familiar with all safety and operating procedures.**
We recommend carrying out operation in a safe environment that includes the use of high voltage signage at all entrances, safety interlocks, and protective glasses.

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Isolated Gate Driver

BM61M41RFV-C Evaluation Board

BM61M41RFV-EVK001

The BM61M41RFV-EVK001 board can be driving MOSFET Power Devices. The Input-side power supply voltage is from 4.5 to 5.5 V. The output-side power supply is from 9 to 24 V. The BM61M41RFV has Power Supply protections which are the Under-Voltage Lockout (UVLO) function at Input-side and Output-side. The Active Miller Clamping is included for gate control. The BM61M41RFV-EVK001 allows designers to evaluate Rohm's Gate Driver family for various applications.

Application

MOSFET Gate Drive

Electric Characteristics

Features and electric characteristics are complied with BM61M41RFV-C. The BM61M41RFV-C datasheet can be referenced to help facilitate designs.

Operating Range

Parameter	Symbol	Min	Max	Units
Input-side Supply Voltage	VCC1*(Note 1)*	4.5	5.5	V
Output-side Supply Voltage	VCC2*(Note 2)*	9	24	V
Operating Temperature	Topr	-40	+125	°C

(Note 1): Relative to GND1
(Note 2): Relative to GND2

Absolute Maximum Ratings

Parameter	Symbol	Limits	Units
Input-side Supply Voltage	VCC1	-0.3 to +7.0*(Note 3)*	V
Output-side Supply Voltage	VCC2	-0.3 to +30.0*(Note 4)*	V
INA Pin Input Voltage	V_{INA}	-0.3 to +VCC1+0.3 or +7.0*(Note 3)*	V
INB Pin Input Voltage	V_{INB}	-0.3 to +VCC1+0.3 or +7.0*(Note 3)*	V

(Note 3): Relative to GND1
(Note 4): Relative to GND2

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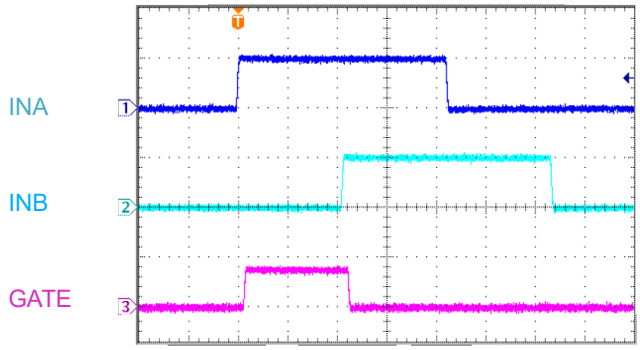
Terminal Descriptions

Terminal name	Description
VCC1	Input-side Power Supply
INA	Input-side Control A
INB	Input-side Control B
GND1	Input-side Ground
GND2	Output-side Ground
GATE	Output-side Gate Control
VCC2	Output-side Power Supply

Input / Output terminal Control

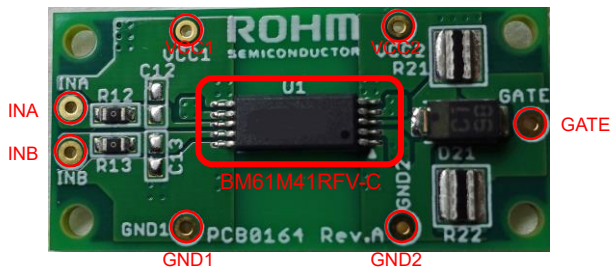
INA (input)	INB (input)	GATE (Output)
L	H	L
H	H	L
L	L	L
H	L	H

Waveform

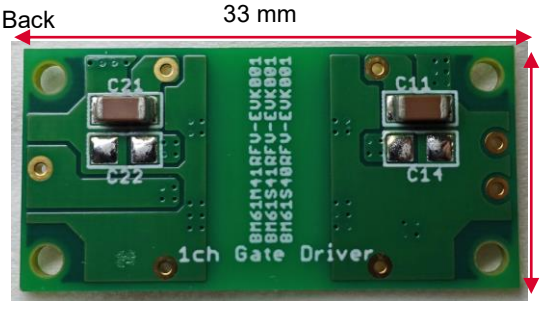


Evaluation Board

Front



Back

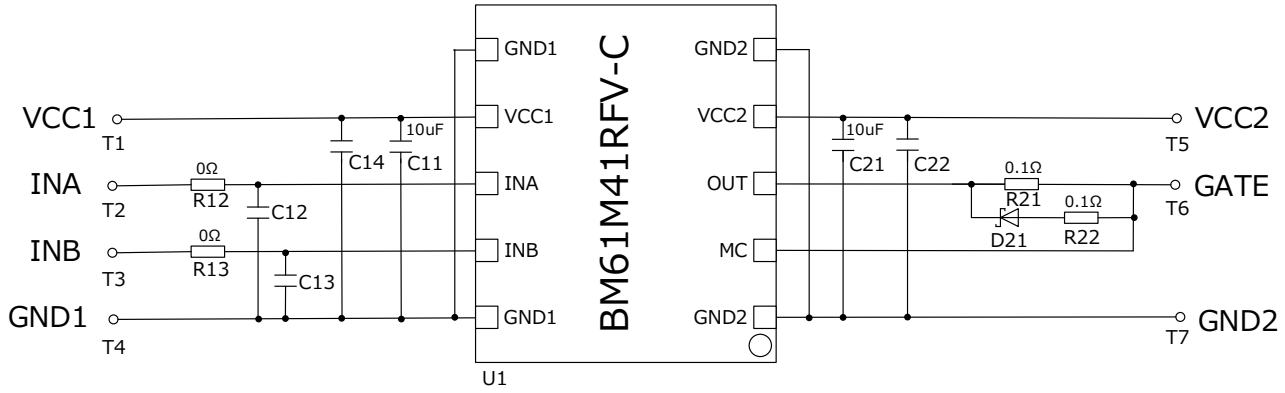


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Schematics

R12, R13, R21 and R22 are implemented interim resisters for shipment check. Please replace each resister which can work with Power Device or input device appropriately.



Bill of Materials

Device	Parts Number	Description	Manufacturer	Parts name	Qty.
Gate Driver	U1	1ch, 9V - 24V	ROHM	BM61M41RFV-C	1
Input Capacitor	C11	10μF, 50V, X7R, 3216	TDK	CGA5L1X7R1H106K160	1
	C14	(no stuff)			0
Input signal filter	R12, R13	0 ohm, 1608	ROHM	MCR03EZPJ000	2
	C12, C13	(no stuff)			0
Output Capacitor	C21	10μF, 50V, X7R, 3216	TDK	CGA5L1X7R1H106K160	1
	C22	(no stuff)			0
Gate	R21	0.1 ohm, 3216	ROHM	LTR18EZPJLR10	1
	R22	0.1 ohm, 3216	ROHM	LTR18EZPJLR10	1
	D21	Schottky Diode, 30V, 5A	ROHM	RBR5L30BDD	1
Test pin	T1, T2, T3, T4, T5, T6, T7 (Option)	(no stuff)	Hirosugi-Keiki	HT-0710-3	7
Spacer	(Option)	M2, 10mm	Hirosugi-Keiki	BSN2010	4
Nut	(Option)	M2	Hirosugi-Keiki	NNT-00	4

Materials may be changed without notice.

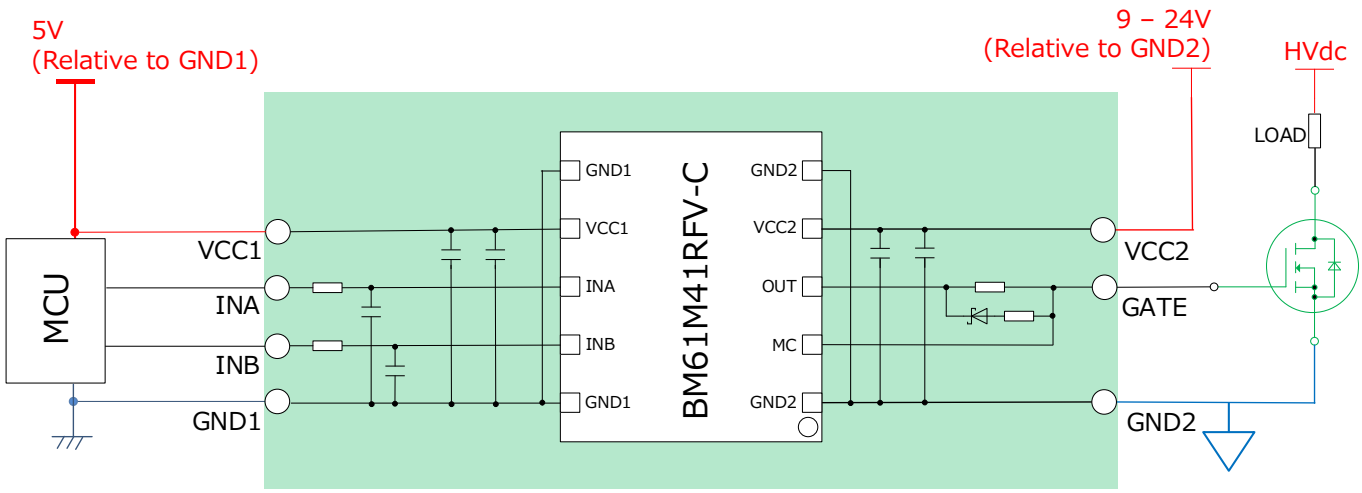
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Application and Operation procedure

Following figure is shown the example application. MOSFET and microcontroller [MCU] are connected to the board via terminals. Please make sure to replace the appropriate value for each resistor and capacitor on the board depends on your applications. The numerous application notes can be referenced to help facilitate designs. Useful application notes are listed on page 6.

Example Application



Equipment

- DC Power Supply: 5 V for control signal [5 VDC], 9 to 24 V for Power Device [9 to 24 VDC]
- Microcontroller [MCU]: Input signal for controlling GATE output
- Power Device: MOSFET
  We have many power devices which can work with Evaluation Board. You can get applicable product information from our web site. Some products are shown on page 7.

Instructions

Before start to connect, make sure to turn off all equipment for your safety.

1. Connect 5 VDC to VCC1–GND terminal on board.
   Stay turn off the power supply.
2. Connect 9 to 24 VDC to VCC2-GND2 terminal on board.
   Stay turn off the power supply.
3. Connect MCU to the INA and INB terminal on board.
   Refer to the Input / Output terminal Control description on page 2.
4. Connect GATE terminal on board to gate terminal on power device.
5. Turn on the 5 VDC and MCU.
6. Turn on the 9 to 24 VDC.

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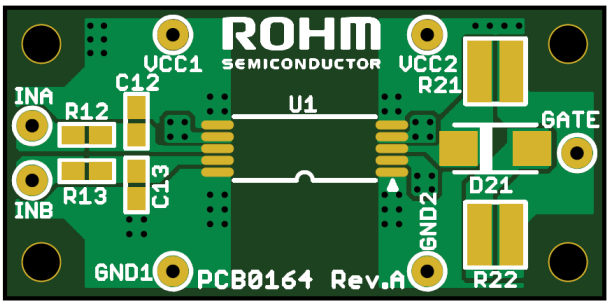
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PCB Layout

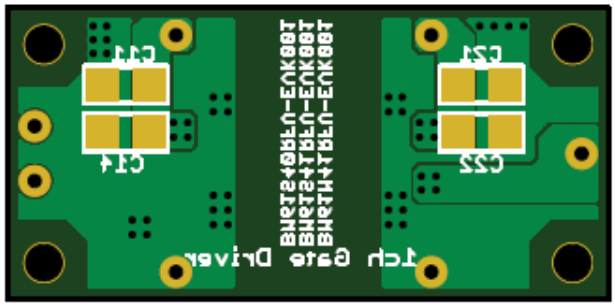
Board size: 33 x 16 mm, Material:FR-4, 4-layer.

Input-side capacitors and output capacitors [C11, C14, C21, C22] are placed on bottom side in order to reduce board size. When you design your PCB layout, we recommend to place them to the same side and near the gate driver as close as possible.

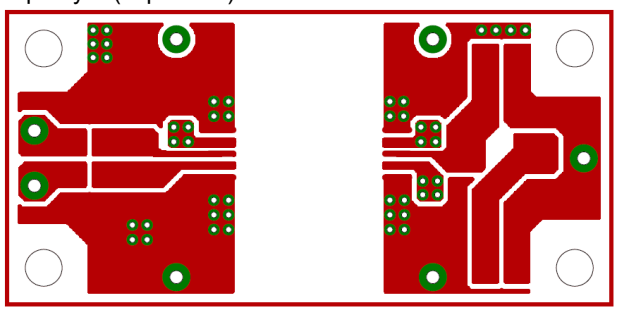
Top Layer with Pads and Silkscreen (Top View)



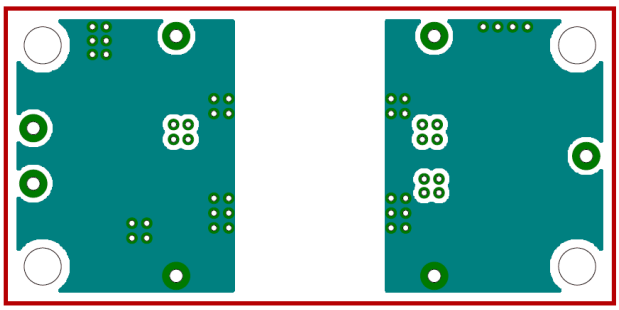
Bottom Layer with Pads and Silkscreen (Top View)



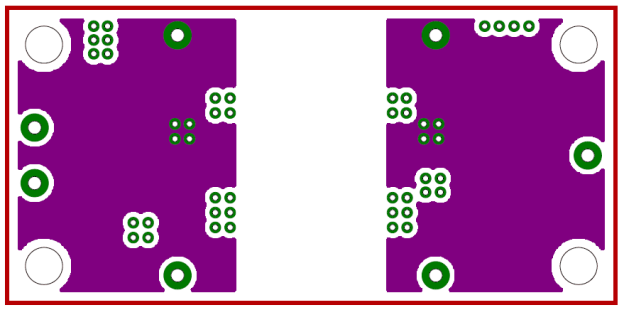
Top Layer (Top View)



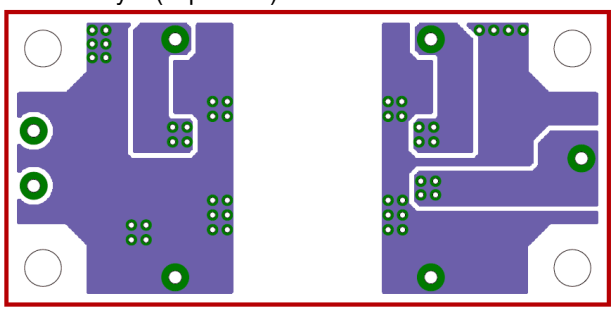
2nd Layer (Top View)



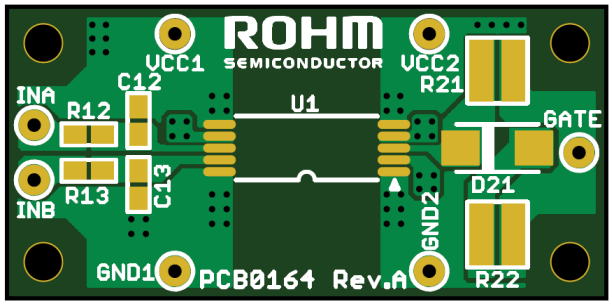
3rd Layer (Top View)



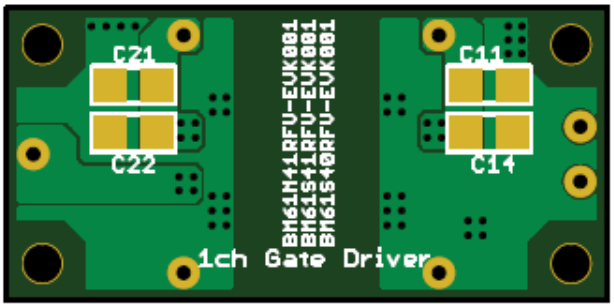
Bottom Layer (Top View)



Silkscreen (Top)



Silkscreen (Bottom)



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We have numerous power devices which are suitable for your requests.
For the MOSFET, please visit our web site below:
https://www.rohm.com/products/transistors/mosfets

Following examples are MOSFET for high-speed switching specifications.

Matching Products	Drain-Source Voltage VDSS[V]	Polarity	Drain Current [A]	RDS(on)[Ohm] VGS=Drive (Typ.)	Drive Voltage [V]	Package code
R6504KNJ	650	Nch	4	0.955	10	TO-263 (D2PAK)
R6507KNJ			7	0.605		
R6509KNJ			9	0.53		
R6511KNJ			11	0.36		
R6515KNJ			15	0.28		
R6520KNJ			20	0.185		
R6524KNJ			24	0.16		
R6504KNX			4	0.955		TO-220FM
R6509KNX			9	0.53		
R6511KNX			11	0.36		
R6515KNX			15	0.28		
R6520KNX			20	0.185		
R6524KNX			24	0.16		
R6530KNX			30	0.125		
R6520KNZ4			20	0.185		TO-247
R6547KNZ4			47	0.07		

We also offer useful power device application notes for design and evaluation.
Please visit our web site below:
https://www.rohm.com/search/application-notes

1. Gate-source voltage behavior in a bridge configuration, No.60AN135E
2. Gate-Source Voltage Surge Suppression Methods, No.62AN010E
3. Snubber circuits design method for SiC MOSFET, No.62AN037E
4. Switching Loss improvement by TO-247-4L with Driver Source, No.62AN04E

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Revision History

Date	Revision Number	Description
2019.10	001	New Release

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Notes

1) The information contained herein is subject to change without notice.

2) Before you use our Products, please contact our sales representative and verify the latest specifications :

3) Although ROHM is continuously working to improve product reliability and quality, semiconductors can break down and malfunction due to various factors.
Therefore, in order to prevent personal injury or fire arising from failure, please take safety measures such as complying with the derating characteristics, implementing redundant and fire prevention designs, and utilizing backups and fail-safe procedures. ROHM shall have no responsibility for any damages arising out of the use of our Poducts beyond the rating specified by ROHM.

4) Examples of application circuits, circuit constants and any other information contained herein are provided only to illustrate the standard usage and operations of the Products. The peripheral conditions must be taken into account when designing circuits for mass production.

5) The technical information specified herein is intended only to show the typical functions of and examples of application circuits for the Products. ROHM does not grant you, explicitly or implicitly, any license to use or exercise intellectual property or other rights held by ROHM or any other parties. ROHM shall have no responsibility whatsoever for any dispute arising out of the use of such technical information.

6) The Products specified in this document are not designed to be radiation tolerant.

7) For use of our Products in applications requiring a high degree of reliability (as exemplified below), please contact and consult with a ROHM representative : transportation equipment (i.e. cars, ships, trains), primary communication equipment, traffic lights, fire/crime prevention, safety equipment, medical systems, servers, solar cells, and power transmission systems.

8) Do not use our Products in applications requiring extremely high reliability, such as aerospace equipment, nuclear power control systems, and submarine repeaters.

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12) When providing our Products and technologies contained in this document to other countries, you must abide by the procedures and provisions stipulated in all applicable export laws and regulations, including without limitation the US Export Administration Regulations and the Foreign Exchange and Foreign Trade Act.

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ROHM SEMICONDUCTOR

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